

LC²MOS High Speed µP-Compatible 8-Bit ADC with Track/Hold Function

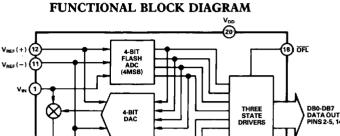
AD7820

AD7820

∩ €NC

FEATURES

Fast Conversion Time: 1.36µs max Built-In Track-and-Hold Function No Missed Codes No User Trims Required Single +5V Supply Ratiometric Operation No External Clock Extended Temperature Range Operation Skinny 20-Pin DIP, SOIC and 20-Terminal Surface Mount Packages



TIMING AND CONTROL

4-BIT FLASH ADC (4LSB)

MODE

GENERAL DESCRIPTION

The AD7820 is a high speed, microprocessor-compatible 8-bit analog-to-digital converter which uses a half-flash conversion technique to achieve a conversion time of $1.36\mu s$. The converter has a 0V to +5V analog input voltage range with a single +5V supply.

The half-flash technique consists of 31 comparators, a most significant 4-bit ADC and a least significant 4-bit ADC. The input to the AD7820 is tracked and held by the input sampling circuitry, eliminating the need for an external sample-and-hold for signals with slew rates less than $100 \text{mV}/\mu \text{s}$.

The part is designed for ease of microprocessor interface with the AD7820 appearing as a memory location or I/O port without the need for external interfacing logic. All digital outputs use latched, three-state output buffer circuitry to allow direct connection to a microprocessor data bus or system input port. A non-three state overflow output is also provided to allow cascading of devices to give higher resolution.

The AD7820 is fabricated in an advanced, all ion-implanted, high speed, Linear Compatible CMOS (LC²MOS) process and features a low maximum power dissipation of 75mW. It is available in 20-pin DIPs, SOICs and in 20-terminal surface mount packages.

PRODUCT HIGHLIGHTS

1. Fast Conversion Time

GND

The half-flash conversion technique, coupled with fabrication on Analog Devices' LC^2MOS process, enables very fast conversion times. The maximum conversion time for the WR-RD mode is 1.36µs, with 1.6µs the maximum for the RD mode.

2. Total Unadjusted Error

The AD7820 features an excellent total unadjusted error figure of less than 1/2LSB over the full operating temperature range. The part is also guaranteed to have no missing codes over the entire temperature range.

3. Built-In Track-and-Hold

The analog input circuitry uses sampled-data comparators, which by nature have a built-in track-and-hold function. As a result, input signals with slew rates up to $100mV/\mu s$ can be converted to 8-bits without external sample-and-hold. This corresponds to a 5V peak-to-peak, 7kHz sine-wave signal.

4. Single Supply

Operation from a single +5V supply with a positive voltage reference allows operation of the AD7820 in microprocessor systems without any additional power supplies.

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AD7820* Product Page Quick Links

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Comparable Parts

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Documentation 🖵

Application Notes

- AN-215: Designer's Guide to Flash-ADC Testing, Part 1, 2 & 3
- AN-299: Simple Circuit Provides Ratiometric Reference Levels for AD782X Family of Half-Flash ADCs

Data Sheet

- AD7820: LC²MOS High Speed µP-Compatible 8-Bit ADC with Track/Hold Function Scanned Data Sheet
- AD7820: Military Data Sheet

Reference Materials

Technical Articles

• MS-2210: Designing Power Supplies for High Speed ADC

Design Resources 🖵

- AD7820 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- · Symbols and Footprints

Discussions 🖵

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(V_{DD} = + 5V; V_{REF} (+) = + 5V; V_{REF} (-) = GND = OV unless otherwise stated). AD7820—SPECIFICATIONS All specifications T_{min} to T_{max} unless otherwise specified. Specifications apply for RD Mode (Pin 7 = 0V)

Parameter	K Version ¹	L Version	B, T Versions	C, U Versions	Units	Conditions/Comment
ACCURACY						
Resolution	8	8	8	8	Bits	
Total Unadjusted Error ²	±1	± 1/2	±1	± 1/2	LSB max	
Minimum Resolution for which						
No Missing Codes are guaranteed	8	8	8	8	Bits	
REFERENCE INPUT						
Input Resistance	1.0/4.0	1.0/4.0	1.0/4.0	1.0/4.0	$k\Omega \min/k\Omega \max$	
V _{REF} (+)Input Voltage Range	$V_{REF}(-)V_{DD}$	$V_{REF}(-)/V_{DD}$	$V_{REF}(-)/V_{DD}$	$V_{REF}(-)/V_{DD}$	V min/V max	
V _{REF} (-) Input Voltage Range	GND/V _{REF} (+)	GND/V _{REF} (+)	GND/V _{REF} (+)	GND/V _{REF} (+)	V min/V max	
NALOGINPUT						
Input Voltage Range	$V_{REF}(-)/V_{REF}(+)$	$V_{REF}(-)/V_{REF}(+)$	$V_{REF}(-)/V_{REF}(+)$	$V_{REF}(-)/V_{REF}(+)$	V min/V max	
Input Leakage Current	±3	±3	± 3	±3	μ A max	
Input Capacitance ³	45	45	45	45	pF typ	
OGIC INPUTS						
CS, WR, RD						
VINH	2.4	2.4	2.4	2.4	V min	
VINL	0.8	0.8	0.8	0.8	V max	
$I_{DNH}(\overline{CS}, \overline{RD})$	1	1	1	1	µA max	
	3	3	3	3	µA max	
InL	-1	-1	-1	-1	µA max	
Input Capacitance ³	8	8	8	8	pFmax	Typically 5pF
MODE					•	
VINH	3.5	3.5	3.5	3.5	V min	
VINL	1.5	1.5	1.5	1.5	V max	
INH	200	200	200	200	μA max	50 µA typ
Ini	-1	-1	-1	-1	µA max	
Input Capacitance ³	8	8	8	8	pFmax	Typically SpF
OGICOUTPUTS						
DB0-DB7, OFL, INT						
V _{OH}	4.0	4.0	4.0	4.0	V min	I _{SOURCE} = 360µA
V _{OL}	0.4	0.4	0.4	0.4	V max	I _{SINK} = 1.6mA
LOUT (DB0-DB7)	±3	± 3	±3	±3	µA max	Floating State Leakage
Output Capacitance ³	8	8	8	8	pFmax	Typically 5pF
RDY	v	•	•		*	- , , - , - , - , - , - , - , - , - , -
VoL	0.4	0.4	0.4	0.4	Vmax	I _{SINK} = 2.6mA
LOUT	±3	±3	±3	±3	μA max	Floating State Leakage
Output Capacitance ³	8	8	8	8	pFmax	Typically 5pF
_ • •		0.2	0.2	0.2	V/µs typ	** * * * *
SLEW RATE, TRACKING ³	0.2	0.2 0.1	0.2	0.2	V/µs typ V/µs max	
	0.1	0.1	V.I	V.1	*/µ31188	
OWER SUPPLY	_					
V _{DD}	5	5	5	5	Volts	± 5% for Specified
_						Performance
I _{DD} ⁴	15	15	20	20	mA max	$\overline{CS} = \overline{RD} = 0V$
Power Dissipation	40	40	40	40	mW typ	
Power Supply Sensitivity	±1/4	± 1/4	± 1/4	± 1/4	LSB max	± 1/16LSB typ
						$V_{DD} = 5V \pm 5\%$

NOTES

NOTES "Temperature Ranges are as follows: K, L Versions: - 40°C to + 85°C B, C Versions: - 40°C to + 85°C T, U Versions: - 55°C to + 125°C "Total Unadjusted Error includes offset, full-scale and linearity errors." "Sample tested at 25°C by Product Assurance to ensure compliance. "See Typical Performance Characteristics.

Specifications subject to change without notice.

TIMING CHARACTERISTICS¹ ($V_{00} = +5V$; $V_{REF}(+) = +5V$; $V_{REF}(-) = GND = 0V$ unless otherwise stated.)

Parameter	Limit at 25°C (All Versions)	Limit at T _{mis} , T _{max} (K, L, B, C Versions)	Limit at T _{min} ,T _{max} (T, U Versions)	Units	Conditions/Comments
t _{CSS}	0	0	0	ns min	$\overline{\text{CS}}$ TO $\overline{\text{RD}}/\overline{\text{WR}}$ Setup Time
t _{CSH}	0	0	0	ns min	CS TO RD/WR Hold Time
t _{RDY} ²	70	90	100	ns max	$\overline{\text{CS}}$ to Delay. Pull-Up
					Resistor 5kΩ.
t _{CRD}	1.6	2.0	2.5	µs max	Conversion Time (RD Mode)
t _{ACC0} 3	t _{CRD} + 20	t _{CRD} + 35	t _{CRD} + 50	ns max	Data Access Time (RD Mode)
t _{INTH} 2	125	_	_	ns typ	RD to INT Delay (RD Mode)
	175	225	225	ns max	
t _{DH} 4	60	80	100	ns max	Data Hold Time
t _P	500	600	600	ns min	Delay Time between Conversions
t _{wr}	600	600	600	ns min	Write Pulse Width
	50	50	50	µs max	
t _{RD}	600	700	700	ns min	Delay Time between \overline{WR} and \overline{RD} Pulses
t _{ACC1} 3	160	225	250	ns max	Data Access Time (WR-RD Mode,
					see Fig. 5b)
t _{R1}	140	200	225	ns max	RD to INT Delay
t _{INTL} ²	700	-	-	ns typ	WR to INT Delay
	1000	1400	1700	ns max	
ACC23	70	90	110	ns max	Data Access Time (WR-RD Mode,
LIHWR ²	100	130	150	ns max	<u>see Fig. 5a)</u> WR to INT Delay (Stand-Alone Operatio
t _{ID}	50	65	75	ns max	Data Access Time after INT
-10	20			ng man	(Stand-Alone Operation)

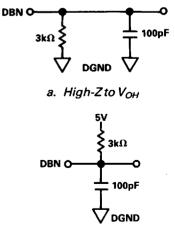
NOTES

Sample tested at 25°C to ensure compliance. All input control signals are specified with tr = tf = 20ns (10% to 90% of +5V) and timed from a voltage level of 1.6V. ${}^{2}C_{L} = 50pF.$

³Measured with load circuits of Figure 1 and defined as the time required for an output to cross 0.8V or 2.4V. ⁴Defined as the time required for the data lines to change 0.5V when loaded with the circuits of Figure 2.

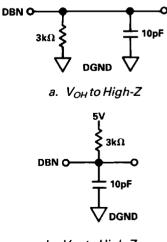
Specifications subject to change without notice.

Test Circuits



b. High-Z to V_{OL}





b. V_{OL} to High-Z

Figure 2. Load Circuits for Data Hold Time Test

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ABSOLUTE MAXIMUM RATINGS*

V_{DD} to GND
Digital Input Voltage to GND
(Pins 6-8, 13) $-0.3V, V_{DD} + 0.3V$
Digital Output Voltage to GND
(Pins 2-5, 9, 14-18) $-0.3V, V_{DD} + 0.3V$
$V_{REF}(+)$ to GND $V_{REF}(-), V_{DD}(+).3V$
$V_{REF}(-)$ to GND $0V, V_{REF}(+)$
V_{IN} to GND
Operating Temperature Range
Commercial (K, L Versions) $\ldots \ldots \ldots -40^{\circ}$ C to $+85^{\circ}$ C
Industrial (B, C Versions) $\dots \dots \dots$
Extended (T, U Versions) $\ldots \ldots \ldots -55^{\circ}C$ to $+125^{\circ}C$

Storage Temperature Range 65°C to -	+ 150°C
Lead Temperature (Soldering, 10secs)	+ 300°C
Power Dissipation (Any Package) to +75°C 4	450mW
Derates above +75°C by	m₩/°C

*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION:

ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are inserted.



Model ¹	Temperature Range	Total Unadjusted Error (Max)	Package Option ²
AD7820KN	-40°C to +85°C	±1LSB	N-20
AD7820LN	-40° C to $+85^{\circ}$ C	± 1/2LSB	N-20
AD7820KP	-40° C to $+85^{\circ}$ C	±1LSB	P-20A
AD7820LP	- 40°C to + 85°C	± 1/2LSB	P-20A
AD7820KR	- 40°C to + 85°C	±1LSB	R-20
AD7820LR	- 40°C to + 85°C	± 1/2LSB	R-20
AD7820BQ	-40°C to +85°C	±1LSB	Q-20
AD7820CQ	- 40°C to + 85°C	$\pm 1/2LSB$	Q-20
AD7820TQ	-55° C to $+125^{\circ}$ C	±1LSB	Q-20
AD7820UQ	-55℃ to +125℃	± 1/2LSB	Q-20
AD7820TE	-55°C to +125°C	±1LSB	E-20A
AD7820UE	- 55°C to + 125°C	± 1/2LSB	E-20A

ORDERING GUIDE

NOTES

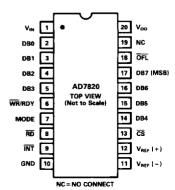
¹To order MIL-STD-883, Class B processed parts, add/883B to part number. Contact your local sales office for military data sheet. For U.S. Standard Military Drawing (SMD), see DESC drawing #5962-88650. ²E = Leadless Ceramic Chip Carrier; N = Plastic DIP; P = Plastic Leaded

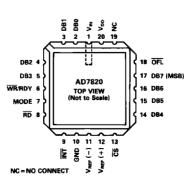
PIN CONFIGURATIONS

LCCC

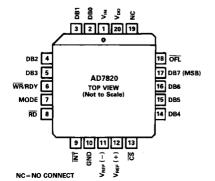
Chip Carrier; Q = Cerdip; R = SOIC.

DIP, SOIC

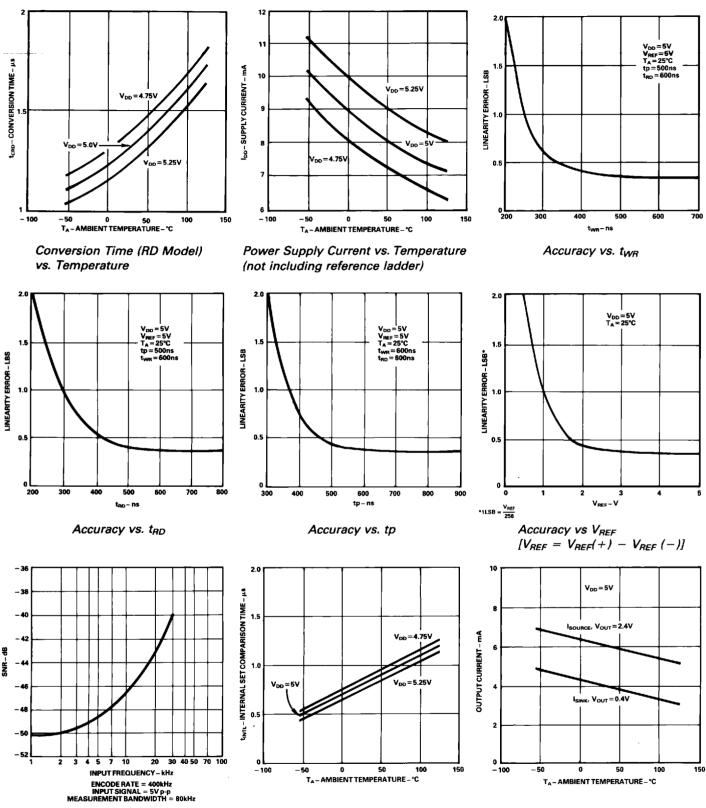




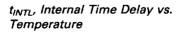
PLCC

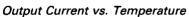


Typical Performance Characteristics—AD7820



Signal-Noise Ratio vs. Input Frequency





PIN FUNCTION DESCRIPTION

PIN MNEMONIC DESCRIPTION

L III	MINEMOINIC	
1	VIN	Analog Input. Range: $V_{REF}(-)$ to
		$V_{\text{REF}}(+)$.
2	DB0	Data Output. Three State Output, bit 0 (LSB)
3	DB1	Data Output. Three State Output, bit 1
4	DB2	Data Output. Three State Output, bit 2
5	DB3	Data Output. Three State Output, bit 3
6	WR/RDY	WRITE control input/READY status
-		output. See Digital Interface section.
7	Mode	Mode Selection Input. It determines
-		whether the device operates in the WR-RD
		or RD mode. It is internally tied to
		GND through a 50µA current source.
		See Digital Interface section.
8	RD	READ Input. RD must be low to access
		data from the part. See Digital Interface
		section.
9	INT	INTERRUPT Output. INT going low
		indicates that the conversion is complete.
		INT returns high on the rising edge
		of \overline{RD} or \overline{CS} . See Digital Interface section.
10	GND	Ground
11	$V_{REF}(-)$	Lower limit of reference span.
		Range: GND $\leq V_{REF}(-) \leq V_{REF}(+)$
12	$V_{REF}(+)$	Upper limit of reference span.
		Range: $V_{REF}(-) \leq V_{REF}(+) \leq V_{DD}$
13	<u>CS</u>	Chip Select Input. \overline{CS} , the decoded
		device address, must be low for
		\overline{RD} or \overline{WR} to be recognized by the
		converter.
14	DB4	Data Output. Three State Output, bit 4
15	DB5	Data Output. Three State Output, bit 5
16	DB6	Data Output. Three State Output, bit 6
17	DB7	Data Output. Three State Output, bit 7 (MSB)
18	OFL	Overflow Output. If the analog input is
		higher than $(V_{REF}(+) - 1/2LSB), \overline{OFL}$
		will be low at the end of conversion. It
		is a non three state output which
		can be used to cascade 2 or more
		devices to increase resolution.
19	NC	No connection.
20	V _{DD}	Power supply voltage, +5V
- •	22	••••

CIRCUIT INFORMATION BASIC DESCRIPTION

The AD7820 uses a half-flash conversion technique whereby two 4-bit flash A/D converters are used to achieve an 8-bit result. Each 4-bit flash ADC contains 15 comparators which compare the unknown input to a reference ladder to get a 4-bit result. For a full 8-bit reading to be realized, the upper 4-bit flash, the most significant (MS) flash, performs a conversion to provide the 4 most significant data bits. An internal DAC, driven by the 4 MSBs, then recreates an analog approximation of the input voltage. This analog result is subtracted from the input, and the difference is converted by the lower flash ADC, the least significant (LS) flash, to provide the 4 least significant bits of the output data. The MS flash ADC also has one additional comparator to detect input overrange.

OPERATING SEQUENCE

The operating sequence for the AD7820 in the WR-RD mode is shown in Figure 3. A set-up time of 500ns is required prior to the falling edge of \overline{WR} . (This 500ns is required between reading data from the AD7820 and starting another conversion). When \overline{WR} is low the input comparators track the analog input signal, V_{IN} . On the rising edge of \overline{WR} , the input signal is sampled and the result for the four most significant bits is latched. INT goes low approximately 700ns after the rising edge of \overline{WR} . This indicates that conversion is complete and the data result is already in the output latch. \overline{RD} going low then accesses the output data. If a faster conversion time is required, the \overline{RD} line can be brought low 600ns after \overline{WR} goes high. This latches the lower 4 bits of data and accesses the output data on DB0-DB7.

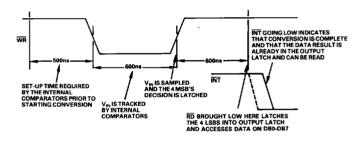


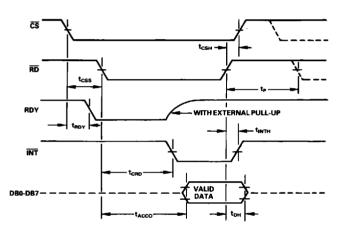
Figure 3. Operating Sequence (WR-RD Mode)

DIGITAL INTERFACE

The AD7820 has two basic interface modes which are determined by the status of the MODE pin. When this pin is low the converter is in the RD mode, with this pin high the AD7820 is set up for the WR-RD mode.

RD Mode

The timing diagram for the RD mode is shown in Figure 4. In the RD mode configuration, conversion is initiated by taking $\overline{\text{RD}}$ low. The $\overline{\text{RD}}$ line is then kept low until output data appears. It is very useful with microprocessors which can be forced into a WAIT state, with the microprocessor starting a conversion, waiting, and then reading data with a single READ instruction. In this mode, pin 6 of the AD7820 is configured as a status output, RDY. This RDY output can be used to drive the processor READY or WAIT input. It is an open drain output (no internal pull-up device) which goes low after the falling edge of $\overline{\text{CS}}$ and goes high impedance at the end of conversion. An $\overline{\text{INT}}$ line is also provided which goes low at the completion of conversion. INT returns high on the rising edge of $\overline{\text{CS}}$ or $\overline{\text{RD}}$.





WR-RD Mode

In the WR-RD mode, pin 6 is configured as the WRITE input for the AD7820. With \overline{CS} low, conversion is initiated on the falling edge of \overline{WR} . Two options exist for reading data from the converter.

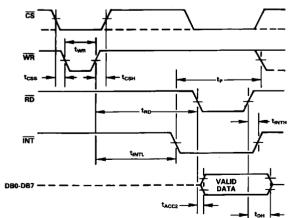


Figure 5a. WR-RD Mode (t_{RD}>t_{INTL})

In the first of these options the processor waits for the \overline{INT} status line to go low before reading the data (see Figure 5a). \overline{INT} typically goes low 700ns after the rising edge of \overline{WR} . It indicates that conversion is complete and that the data result is in the output latch. With \overline{CS} low, the data outputs (DB0-DB7) are activated when \overline{RD} goes low. \overline{INT} is reset by the rising edge of \overline{RD} or \overline{CS} .

The alternative option can be used to shorten the conversion time. To achieve this, the status of the \overline{INT} line is ignored and \overline{RD} can be brought low 600ns after the rising edge of \overline{WR} . In this case \overline{RD} going low transfers the data result into the output latch and activates the data outputs (DB0-DB7). \overline{INT} also goes low on the falling edge of \overline{RD} and is reset on the rising edge of \overline{RD} or \overline{CS} . The timing for this interface is shown in Figure 5b.

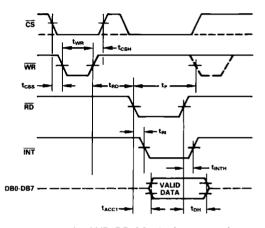


Figure 5b. WR-RD Mode (t_{RD}<t_{INTL})

The AD7820 can also be used in stand-alone operation in the WR-RD mode. \overline{CS} and \overline{RD} are tied low and a conversion is initiated by bringing \overline{WR} low. Output data is valid typically 700ns after the rising edge of \overline{WR} . The timing diagram for this mode is shown in Figure 6.

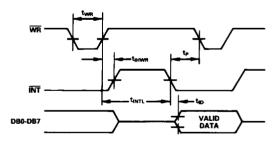


Figure 6. WR-RD Mode Stand-Alone Operation, $\overline{CS} = \overline{RD} = 0$

APPLYING THE AD7820 REFERENCE AND INPUT

The two reference inputs on the AD7820 are fully differential and define the zero to full-scale input range of the A/D converter. As a result, the span of the analog input can easily be varied since this range is equivalent to the voltage difference between $V_{IN}(+)$ and $V_{IN}(-)$. By reducing the reference span, $V_{REF}(+)$ - $V_{REF}(-)$, to less than 5V the sensivity of the converter can be increased (i.e., if $V_{REF} = 2V$ then 1LSB = 7.8mV). The input/reference arrangement also facilitates ratiometric operation.

This reference flexibility also allows the input span to be offset from zero. The voltage at $V_{REF}(-)$ sets the input level which produces a digital output of all zeroes. Therefore, although V_{IN} is not itself differential, it will have nearly differential-input capability in most measurement applications because of the reference design. Figure 7 shows some of the configurations that are possible.

INPUT CURRENT

Due to the novel conversion techniques employed by the AD7820, the analog input behaves somewhat differently than in conventional devices. The ADC's sampled-data comparators take varying amounts of input current depending on which cycle the conversion is in.

The equivalent input circuit of the AD7820 is shown in Figure 8a. When a conversion starts (\overline{WR} low, WR-RD mode), all input switches close, and V_{IN} is connected to the most significant and least significant comparators. Therefore, V_{IN} is connected to thirty one 1pF input capacitors at the same time.

The input capacitors must charge to the input voltage through the on resistance of the analog switches (about $2k\Omega$ to $5k\Omega$). In addition, about 12pF of input stray capacitance must be charged. For large source resistances, the analog input can be modelled as an RC network as shown in Figure 8b. As R_S increases, it takes longer for the input capacitance to charge.

In the RD mode, the time for which the input comparators track the analog input is 600ns at the start of conversion. In the WR-RD mode the input comparators track V_{IN} for the duration of the WR pulse. Since other factors cause this time to be at least 600ns, input time constants of 100ns can be accommodated without special consideration. Typical total input capacitance values of 45pF allow R_S to be 1.5k Ω without lengthening WR to give V_{IN} more time to settle.

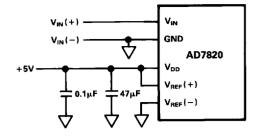


Figure 7a. Power Supply as Reference

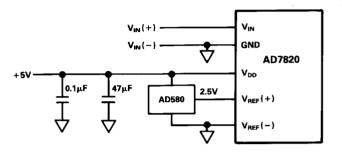


Figure 7b. External Reference 2.5V Full-Scale

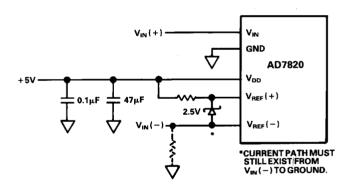


Figure 7c. Input Not Referenced to GND

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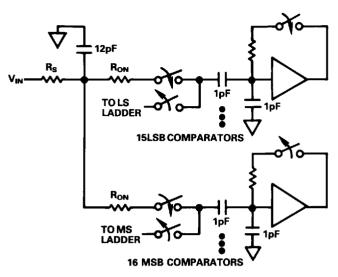


Figure 8a. AD7820 Equivalent Input Circuit

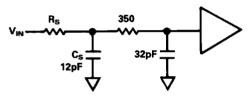


Figure 8b. RC Network Model

INPUT FILTERING

It should be made clear that transients on the analog input signal, caused by charging current flowing into $V_{\rm IN}$ will not normally degrade the ADC's performance. In effect, the AD7820 does not "look" at the input when these transients occur. The

Applications

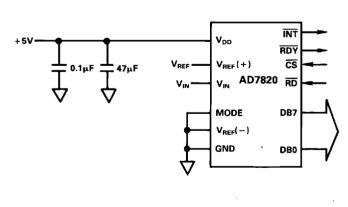


Figure 9a. 8-Bit Resolution

comparators' outputs are not latched while \overline{WR} is low, so at least 600ns will be provided to charge the ADC's input capacitance. It is therefore not necessary to filter out these transients with an external capacitor at the V_{IN} terminal.

INHERENT SAMPLE-HOLD

A major benefit of the AD7820's input structure is its ability to measure a variety of high speed signals without the help of an external sample-and-hold. In a conventional SAR type converter, regardless of its speed, the input must remain stable to at least 1/2LSB throughout the conversion process if full accuracy is to be maintained. Consequently, for many high speed signals, this signal must be externally sampled and held stationary during the conversion. The AD7820 input comparators, by nature of their input switching inherently accomplish this sample-and-hold function. Although the conversion time for the AD7820 is 1.36µs, the time through which V_{IN} must be $\frac{1}{2}LSB$ stable is much smaller. The AD7820 "samples" V_{IN} only when \overline{WR} is low. The value of V_{IN} approximately 100ns (internal propogation delay) after the rising edge of \overline{WR} is the measured value. This value is then used in the least significant flash to generate the lower 4-bits of data.

Input signals with slew rates typically below 200mV/ μ s can be converted without error. However, because of the input time constants, and charge injection through the opened comparator input switches, faster signals may cause errors. Still, the AD7820's loss in accuracy for a given increase in signal slope is far less than what would be witnessed in a conventional successive approximation device. A SAR type converter with a conversion time as fast as 1 μ s would still not be able to measure a 5V, 1kHz sine wave without the aid of an external sample-and-hold. The AD7820 with no such help, can typically measure 5V, 10kHz waveforms.

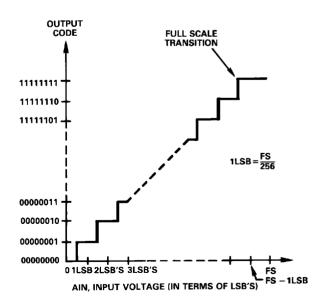
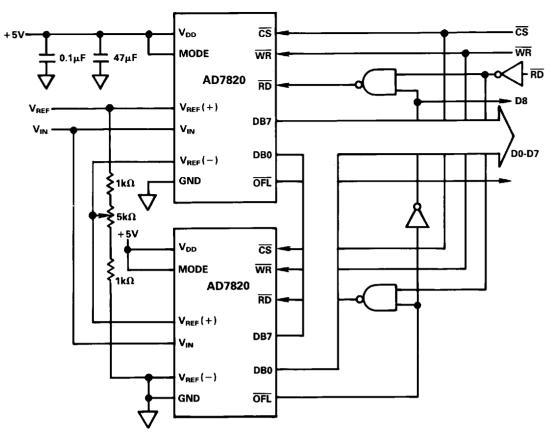


Figure 9b. Nominal Transfer Characteristic for 8-Bit Resolution Circuit





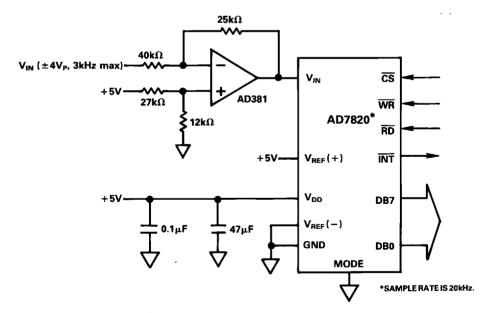
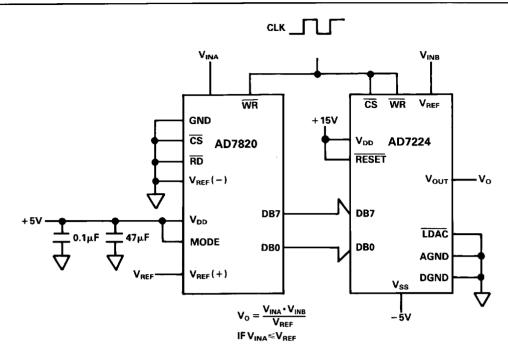


Figure 11. Telcom A/D Converter





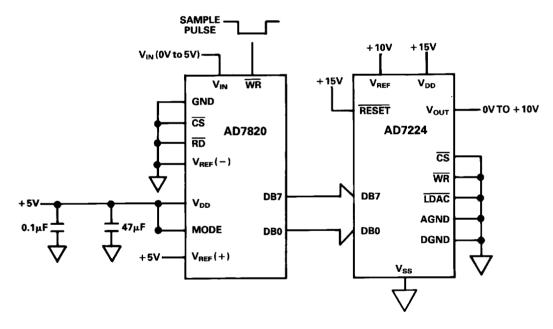
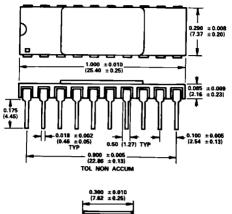


Figure 13. Fast Infinite Sample-and-Hold

MECHANICAL INFORMATION OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

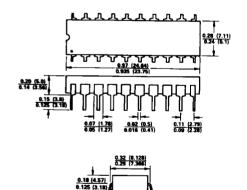
20-PIN CERAMIC¹





NOTES: 1. LEAD NUMBER 1 IDENTIFIED BY DOT OR NOTCH. 2. LEADS WILL BE EITHER GOLD OR TIN PLATED IN ACCORDANCE WITH MIL-M-30610 REQUIREMENTS.

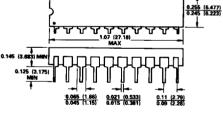
20-PIN CERDIP (SUFFIX Q)



0.011 (0.28



20-PIN PLASTIC DIP (SUFFIX N)





NOTE

¹Analog Devices reserves the right to ship ceramic packages in lieu of cerdip packages.

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